

Green Products

Technical Data Data Sheet N0823, Rev. B

MBRF1080CTL SCHOTTKY RECTIFIER

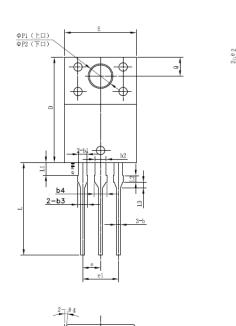
Applications:

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection

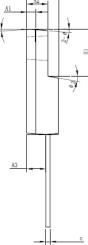
Features:

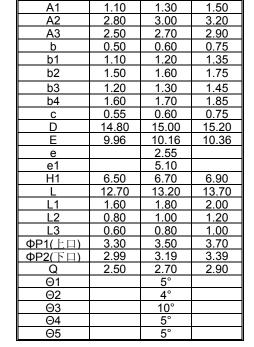
- 150°C TJ operation
- Center tap configuration
- Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- Terminals: pure tin plated, solderable per MIL-STD-750, Method 2026
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Mechanical Dimensions (In mm):



ահուտիս տիս





MIN.

4.30

TYP.

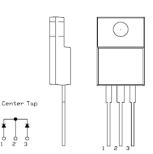
4.50

SYMBOL

A

ITO-220AB

- China Germany Korea Singapore United States •
- http://www.smc-diodes.com sales@ smc-diodes.com •



OUTLINE DRAWING

MAX.

4.70



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Where XXXXX is YYWWL

= Device Type

= Package type

= Configuration

= Lot Number

= SSG

= Year

= Week

= Forward Current (10A)

= Reverse Voltage (80V)

MBR

F

10

80 CTL

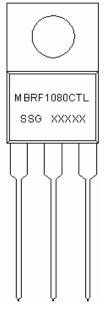
SSG YY

WW

L

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Marking Diagram:



Cautions: Molding resin Epoxy resin UL:94V-0

Ordering Information:

Device	Package	Shipping
MBRF1080CTL	ITO-220AB	50pcs / tube
	(Pb-Free)	sopes / tube

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification.

Maximum Ratings:

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	-	80	V
Average Rectified Forward Current	I _{F (AV)}	50% duty cycle @T _c =133°C, rectangular wave form	5(Per leg) 10(Per device)	A
Peak One Cycle Non-Repetitive Surge Current (per leg)	I _{FSM}	8.3 ms, half Sine pulse	125	А

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Electrical Characteristics:

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop	V _{F1}	@ 5A, Pulse, T _J = 25 °C	0.70	0.75	V
(per leg)*	V _{F2}	@ 5A, Pulse, T _J = 125 °C	0.59	0.64	V
Reverse Current at DC condition (per leg)*	I _{R1}	$@V_R = rated V_R$ T _J = 25 °C	0.06	1.0	mA
Reverse Current (per leg)*	I _{R2}	$@V_R = rated V_R$ T _J = 125 °C	11	30	mA
Junction Capacitance (per leg)	CT	@V _R = 5V, T _C = 25 °C f _{SIG} = 1MHz	120	220	pF
Series Inductance (per leg)	L _S	Measured lead to lead 5 mm from package body	8.0	-	nH
Voltage Rate of Change	dv/dt	-	-	10,000	V/μs

* Pulse Width < 300µs, Duty Cycle <2%

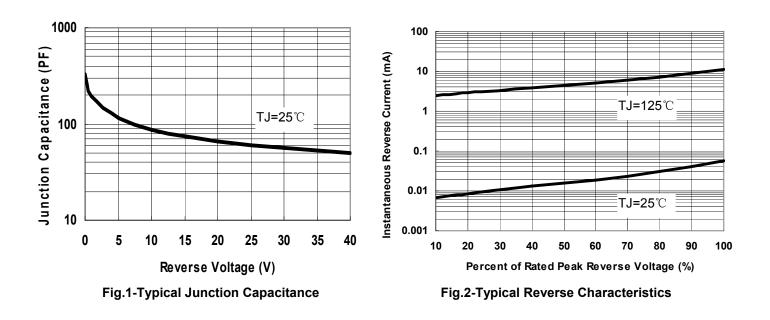
Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	TJ	-	-55 to +150	°C
Storage Temperature	T _{stg}	-	-55 to +150	°C
Typical Thermal Resistance Junction to Case (per leg)	R _{θJC}	DC operation	3.5	°C/W
Approximate Weight	wt	-	2	g
Case Style		ITO-220AB		



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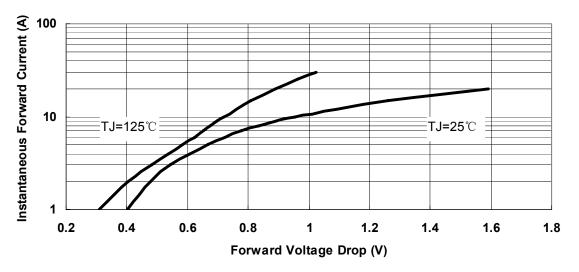


Fig.3-Typical Instantaneous Forward Voltage Characteristics



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